

## 25 MIPS, 8 kB Flash, 10-Bit ADC, 20-Pin Mixed-Signal MCU

## Analog Peripherals 10-Bit ADC

- Programmable throughput up to 200 ksps
- Up to 16 external inputs; programmable as single-ended or differential
- Reference from internal  $V_{\text{REF}}$ ,  $V_{\text{DD}}$ , or external pin
- Internal or external start of conversion sources
- Built-in temperature sensor (±3 °C)

## 10-bit DAC (Current Mode)

## Comparator

- Programmable hysteresis and response time
- Configurable to generate interrupts or reset
- Low current (0.4 µA)

## **On-Chip Debug**

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watchpoints
- Inspect/modify memory, registers, and stack
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

## Supply Voltage: 2.7 to 3.6 V

- Typical operating current: 6.4 mA at 25 MHz
  9 µA at 32 kHz
- Typical stop mode current: <0.1 μA</li>

### Temperature Range: -40 to +85 °C

## High-Speed 8051 µC Core

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 25 MIPS throughput with 25 MHz clock
- Expanded interrupt handler

#### Memory

- 768 bytes data RAM
- 8 kB Flash; in-system programmable in 512 byte sectors (512 bytes are reserved)

## **Digital Peripherals**

- 17 port I/O; all are 5 V tolerant
- Hardware SMBus<sup>™</sup> (I2C<sup>™</sup> compatible), SPI<sup>™</sup>, and UART serial ports available concurrently
- Programmable 16-bit counter/timer array with three capture/compare modules, WDT
- 4 general-purpose 16-bit counter/timers
- Real-time clock mode using PCA or timer and external clock source

## **Clock Sources**

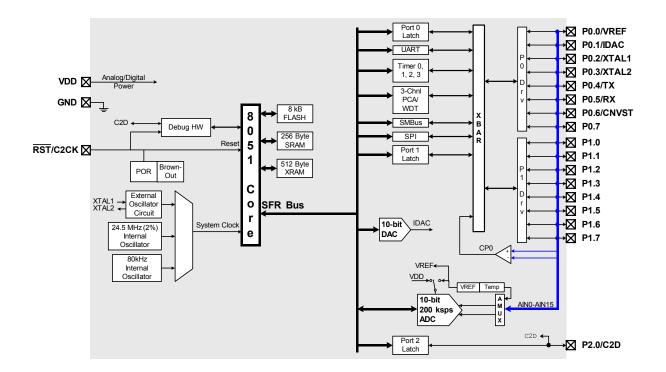
- Two internal oscillators:
  - -24.5 MHz, 2% accuracy supports UART operation
  - -80 kHz low frequency, low-power
- External oscillator: Crystal, RC, C, or Clock (1 or 2 pin modes)
- Can switch between clock sources on-the-fly

## **Package**

- 20-pin DIP (lead-free package)

#### **Ordering Part Numbers**

- C8051F330D-GP



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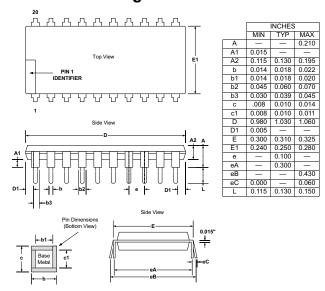
## **Selected Electrical Specifications**

 $(T_A = -40 \text{ to } +85 \text{ C}^{\circ}, \text{VDD} = 2.7 \text{ V} \text{ unless otherwise specified})$ 

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
GLOBAL CHARACTERIS	Tics				
Supply Voltage		2.7		3.6	V
Supply Current with	Clock = 25 MHz		6.4		mA
CPU active	Clock = 1 MHz		0.36		mA
	Clock = 80 kHz; V <sub>DD</sub> Monitor Disabled		20		μΑ
	Clock = 32 kHz; V <sub>DD</sub> Monitor Disabled		9		μA
Supply Current (shutdown)	Oscillator off; V <sub>DD</sub> Monitor Disabled		<0.1		μA
Clock Frequency Range		DC		25	MHz
INTERNAL OSCILLATORS	S				
Frequency (OSC0)		24.0	24.5	25.0	MHz
Frequency (OSC1)	Note 1		80		kHz
A/D CONVERTER					
Resolution			10		bits
Integral Nonlinearity			±1/2	±1	LSB
Differential Nonlinearity	Guaranteed Monotonic		±1/2	±1	LSB
Signal-to-Noise Plus		53	55.5		dB
Distortion					
Throughput Rate				200	ksps
Input Voltage Range		0		$V_{REF}$	V
D/A CONVERTER					
Resolution			10		bits
Integral Nonlinearity			±1/2		LSB
Differential Nonlinearity	Guaranteed Monotonic		±1/2	±1	LSB
Output Settling Time			5		μs
COMPARATOR					
Response Time Mode0	(CP+) - (CP-) = 100  mV		0.1		μs
Current Consumption Mode0			7.6		μA
Response Time Mode1	(CP+) - (CP-) = 100  mV		0.18		μs
Current Consumption Mode1			3.2		μA
Response Time Mode2	(CP+) - (CP-) = 100  mV		0.32		μs
Current Consumption Mode2			1.3		μA
Response Time Mode3	(CP+) - (CP-) = 100  mV		1		μs
Current Consumption Mode3			0.4		μΑ

Note 1: OSC1 can be calibrated in 2.5% steps using an internal calibration register.

# **Package Information**



# C8051F330DK Development Kit

